TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC164AFN

8-Bit Shift Register (S-IN, P-OUT)

The TC74HC164A is a high speed CMOS 8-BIT SERIAL-IN PARALLEL-OUT SHIFT REGISTER fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

It consists of a serial-in, parallel-out 8-bit shift register with a CK input and an overriding $\overline{\text{CLR}}$ input.

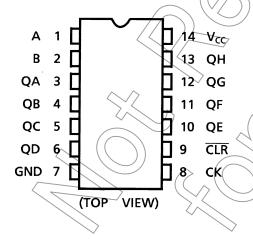
Two serial data inputs (A, B) are provided so that one may be used as a data enable.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

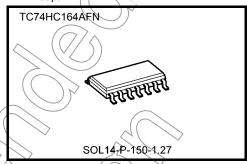
Features

- High speed: $f_{max} = 58 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25^{\circ}C$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Outputs drive capability: 10 LSTTL loads
- Symmetrical output impedance: | IOH | = IOL = 4 mA (min)
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) $\neq 2$ to 6
- Pin and function compatible with 74LS164

Pin Assignment



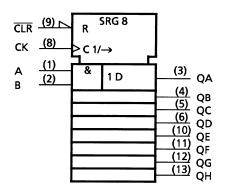
Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight SOL14-P-150-1.27

:)0.12 g (typ.)

IEC Logic Symbol

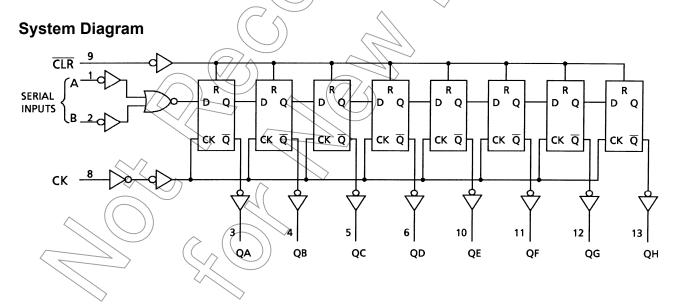


Truth Table

	Inp	uts		Outputs						
CLR	СК	Seria	al IN	QA	QB		QH			
		Α	В	QA			QΠ			
L	Х	Х	Х	L	L		L			
Н		Х	Х	No Change						
Н		L	Х	L	QA _n		QGn			
Н		Х	L	L	QA _n		QGn			
Н		Н	Н	Н	QA _n		QGn			

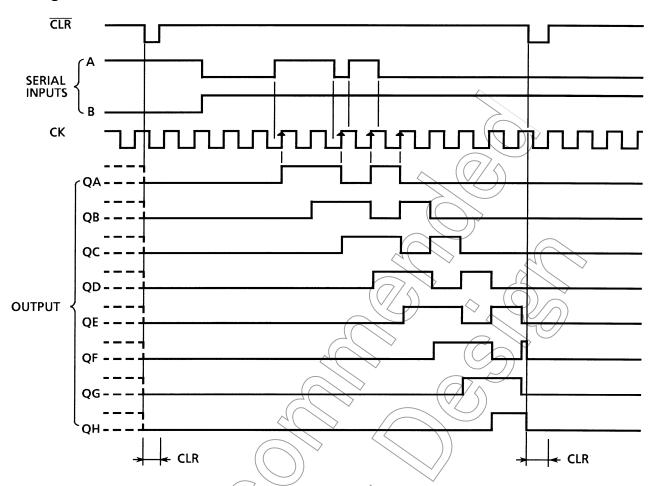
X: Don't care

QA_n~QG_n: The level of QA~QG, respectively, before the most recent positive edge of clock.



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Timing Chart



Absolute Maximum Ratings (Note)

Characteristics	Sýmbol	Rating	Unit
Supply voltage range	V _{CC}	(V
DC input voltage	→ V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	VouT	-0.5 to V _{CC} + 0.5	٧
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Joc	±50	mA
Power dissipation	RD	180	mW
Storage temperature	J _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

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Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	< ∨
Operating temperature	T _{opr}	-40 to 85	S
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	$\langle \ \rangle)$

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

				- \ \ / /		<u> </u>	- / /-	$\mathcal{A}\mathcal{A}\mathcal{A}$	_	
Characteristics	Symbol		Test Condition			Га = 25°C			a)= o 85°C	Unit
				VCC (W)	Min	Typ.	Max	Min	Max	
				2.0	1.50	_((\mathcal{I})	1.50	_	
High-level input voltage	V_{IH}		-	4.5	3.15	7/		3.15	_	V
l				6.0	4.20	(\checkmark)) —	4.20	_	
			4(0)	2.0	_/	\ <u> </u>	0.50	_	0.50	
Low-level input voltage	V_{IL}			4.5	_ `))—	1.35	_	1.35	V
		((6.0	\-\/	/-	1.80	_	1.80	
	Voн	V _{IN} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			I _{OH} = -20 μA	4.5	4.4	4.5	_	4.4	_	
High-level output voltage			_	6.0	5.9	6.0	_	5.9	_	V
			I _{OH} = -4 mA	4.5	4.18	4.31	_	4.13	_	
			I _{OH} = -5.2 mA	6.0	5.68	5.80	_	5.63	_	
				2.0	_	0.0	0.1	_	0.1	
		V _{IN} = V _{IH} or V _{IL}	LoL = 20 μA	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage				6.0	_	0.0	0.1	_	0.1	V
		^	$I_{OL} = 4 \text{ mA}$	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Input leakage current)) I _{IN}	VIN=ACC OL	GND	6.0	_	_	±0.1	_	±1.0	μΑ
Quiescent supply current	lcc	VIN = VCC or	GND	6.0	_	_	4.0	_	40.0	μА

Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°0		25°C	Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width	5 a.s		2.0	_	75	95	
(CK)	t _{W (L)}	_	4.5	/-	15	19	ns
(CK)	t _{W (H)}		6.0		13	16	
Minimum pulse width			2.0	(F)	80	100	
(CLR)	t _{W (L)}	_	4.5) ₁	16	20	ns
(OLN)		<	6.0	\mathcal{A}	14	17	
Minimum set-up time			2.0	_	50	65	
(A, B)	ts	_	4.5	_	10	13	ns
(11, 12)			6.0	_	9	11	
Minimum hold time			2.0		<15 √5	5	
(A, B)	t _h	- (7)	→ 4.5	-6	5	> 5	ns
(1, 5)			6.0 🔷	7)5	5	
Minimum removal time			2.0		5/	5	
(CLR)	t _{rem}		4.5	/	> 5	5	ns
(OLIV)			6.0	$\langle \mathcal{A} \rangle$	5	5	
			(2.0) \	\sim	6	5	
Clock frequency	f	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	4.5	<i>/</i> –	31	25	MHz
			6.0	_	36	29	

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, $Ta = 25^{\circ}\text{C}$, input: $t_r = t_f = 6 \text{ ns}$)

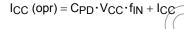
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH}		_	4	8	ns
Propagation delay time (CK-Qn)	t _{pLH}	<u> </u>	_	15	27	ns
Propagation delay time (CLR -Qn)	t _{pHL}	_	_	16	30	ns
Maximum clock frequency	f _{max}	_	33	58	_	MHz

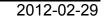
AC Characteristics (C $_{L}=50\ pF,$ input: $t_{r}=t_{f}=6\ ns)$

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°		Unit
	· ,		V _{CC} (V)	Min	Тур.	Max	Min	Max	
Output transition time	tтLH tтнL	_	2.0 4.5 6.0	_ _ _	25 7 6	75 15 13		95 19 16	ns
Propagation delay time (CK-Qn)	t _{pLH}	_	2.0 4.5 6.0	_ _ _	57 19	160 32 27		200 40 34	ns
Propagation delay time (CLR -Qn)	t _p HL	_	2.0 4.5 6.0	-((60 20 17	175 35 30		220 44 37	ns
Maximum clock frequency	f _{max}	_	2.0 4.5 6.0	6 31 36	18 53 62	- -	5 25 29	> -	MHz
Input capacitance	C _{IN}	_		<i>)}</i>	5 🔷	10) 10	pF
Power dissipation capacitance	C _{PD} (Note)	-		_	107	71(0	\$ <u></u>	_	pF

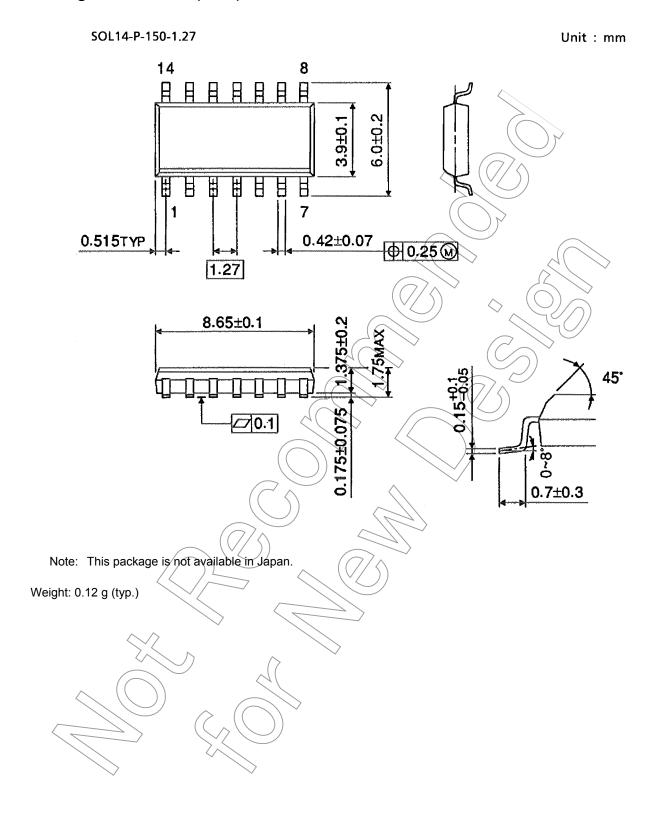
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:





Package Dimensions (Note)



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